

TPDVxx25

25 A high voltage Triacs

Features

- On-state current (I_{T(RMS)}): 25 A
- Max. blocking voltage (V_{DRM}/V_{RRM}): 1200 V
- Gate current (I_{GT}): 150 mA
- Commutation @ 10 V/µs: up to 88 A/ms
- Noise immunity: 2 kV/µs
- Insulated package:
 - 2,500 V rms (UL recognized: E81734).

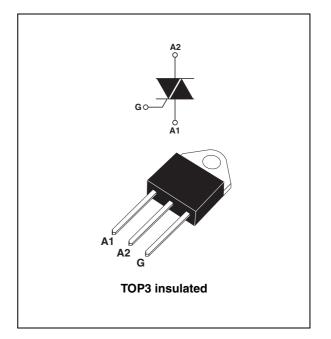
Description

The TPDVxx25 series use high performance alternistor technology.

Featuring very high commutation levels and high surge current capability, these devices are well adapted to power control for inductive and resistive loads (motor, transformer...) especially on three-phase power grid. Targeted three-phase applications include heating systems, motor starters, and induction motor speed control (especially for fans).

Table 1.Device summary

Parameter	TPDV825RG	TPDV1025RG	TPDV1225RG		
Blocking voltage V _{DRM} /V _{RRM}	800 V	1000 V	1200 V		
On-state current I _{T(RMS)}	25 A				
Gate current I _{GT}	150 mA				



1 Characteristics

Symbol	Parameter			Value	Unit	
I _{T(RMS)}	On-state rms current (180° conduction	angle)	angle) $T_c = 85 \ ^{\circ}C$		А	
	Non repetitive surge peak on-state current	t _p = 2.5 ms		390		
I _{TSM}		t _p = 8.3 ms	T _j = 25 °C	250	А	
		t _p = 10 ms		230		
l ² t	I ² t value for fusing	t _p = 10 ms	T _j = 25 °C	265	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 500 \text{ mA}, \text{ dI}_G/\text{dt} = 1 \text{ A/}\mu\text{s}$	F = 50 Hz		100	A/µs	
		TPDV825		800		
V _{DRM} V _{RRM}	Repetitive peak off-state voltage	TPDV1025	T _j = 125 °C	1000	V	
• RRIM		TPDV1225		1200		
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C	
V _{INS(RMS)} ⁽¹⁾	Insulation rms voltage			2500	V	

Table 2. Absolute maximum ratings (limiting values)

1. A1, A2, gate terminals to case for 1 minute

Table 3.Electrical Characteristics (T_i = 25 °C, unless otherwise specified)

Symbol	Test conditions		Quadrant		Value	Unit
I _{GT}			1 - 11 - 111	MAX.	150	mA
V _{GT}	$V_D = 12 \text{ V DC}, \text{ R}_L = 33 \Omega$		1 - 11 - 111	MAX.	1.5	V
V _{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$	T _j = 125 °C	- -	MIN.	0.2	V
t _{gt}	$V_D = V_{DRM} I_G = 500 \text{ mA} \text{ d}I_G/\text{d}t = 3 \text{ A/}\mu\text{s}$		- -	TYP.	2.5	μs
I _H ⁽¹⁾	I _T = 500 mA Gate open			TYP.	50	mA
1	L _ 10x1		I - III	TYP.	100	mA
١L	$I_{G} = 1.2 \times I_{GT}$	II	200			
dV/dt	Linear slope up to: $V_D = 67\% V_{DRM}$ Gate open $T_j = 125 \degree C$			MIN.	2000	V/µs
V _{TM} ⁽¹⁾	I _{TM} = 35 A t _p = 380 μs			MAX.	1.8	V
V _{to} ⁽¹⁾	Threshold voltage $T_j = 125 \text{ °C}$			MAX.	1.1	V
R _d ⁽¹⁾	Dynamic resistance $T_j = 125 \text{ °C}$			MAX.	19	mΩ
I _{DRM}	$V_{DRM} = V_{RRM} \qquad \qquad \frac{T_j = 25 \text{ °C}}{T_j = 125 \text{ °C}}$				20	μA
I _{RRM}			1	MAX.	8	mA
(dl/dt)c ⁽¹⁾	(dV/dt)c = 200 V/µs		N ALM	MIN.	20	A /mac
	(dV/dt)c = 10 V/µs	— T _j = 125 °C		IVIIIN.	88	A/ms

1. For either polarity of electrode A_2 voltage with reference to electrode A_1 .



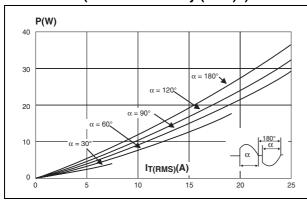
Symbol	Parameter		Value	Unit
P _{G(AV)}	Average gate power dissipation		1	W
P _{GM}	Peak gate power dissipation	t _p = 20 μs	40	W
I _{GM}	Peak gate current $t_p = 20 \ \mu s$		8	А
V _{GM}	Peak positive gate voltage	t _p = 20 μs	16	V

Table 4. Gate characteristics (maximum values)

Table 5.Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient	50	°C/W
R _{th(j-c)} DC	Junction to case for DC	1.5	°C/W
R _{th(j-c)} AC	Junction to case for 360 °Conduction angle (F = 50 Hz)	1.1	°C/W

Figure 1. Max. rms power dissipation versus Figure 2. on-state rms current (F = 50Hz). (curves limited by (dl/dt)c)



Max. rms power dissipation and max. allowable temperatures $(T_{amb} \text{ and } T_{case})$ for various R_{th}

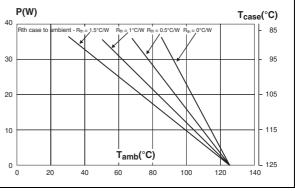


Figure 3. On-state rms current versus case temperature

Figure 4. Relative variation of thermal impedance versus pulse duration

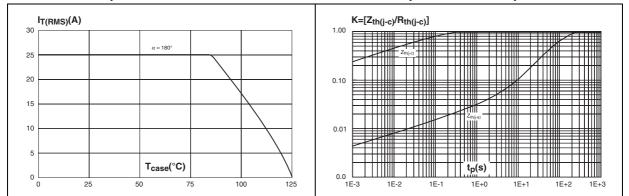


Figure 6. Non repetitive surge peak on-state current versus number of cycles

TPDVxx25

1000

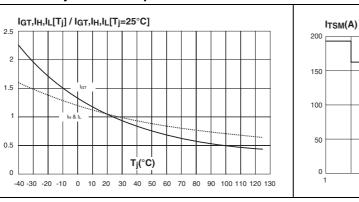
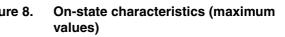


Figure 7. Non-repetitive surge peak on-state Figure 8. current for a sinusoidal pulse and corresponding values of I²t



Number of cycles

10

100

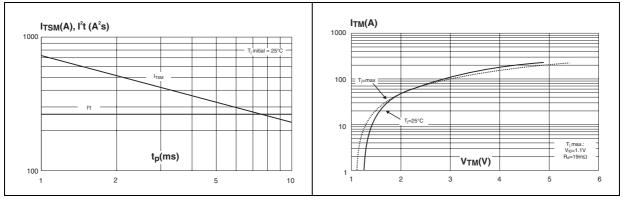
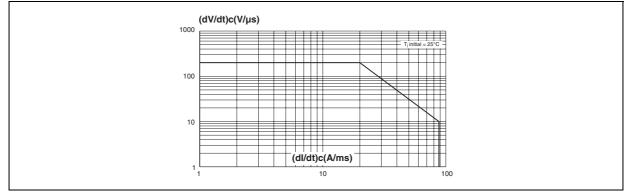


Figure 9. Safe turn-off operating area



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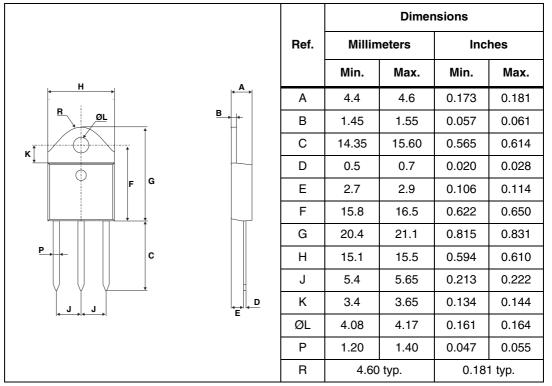


2 Package information

- Epoxy meets UL94,V0
- Cooling method: C (by conduction)
- Recommended torque value: 0.9 to 1.2 N·m

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Table 6.TOP3 insulated dimensions





3 Ordering information

Table 7.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
TPDV825RG	TPDV825				
TPDV1025RG	TPDV1025	TOP3 insulated	4.5 g	30	Tube
TPDV1225RG	TPDV1225				

4 Revision history

Table 8. Document revision history

Date	Revision	Changes	
30-Mar-2011	1	First issue.	
13-Jan-2012	2	Updated dl/dt in <i>Table 2</i> and added V _{to} and R _d to <i>Table 3</i> .	



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